

TENTATIVE

TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

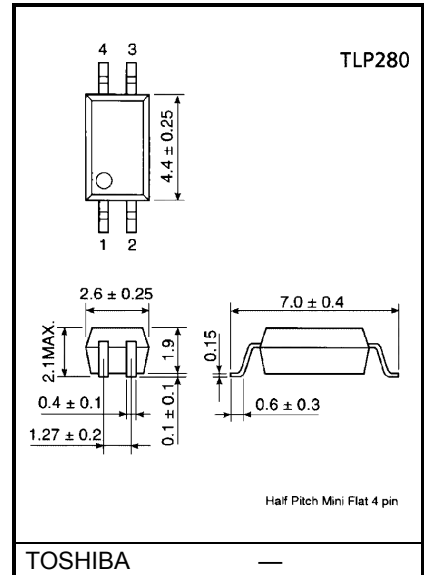
TLP280, TLP280-4

Programmable Controllers
 AC/DC-Input Module
 PC Card Modem (PCMCIA)

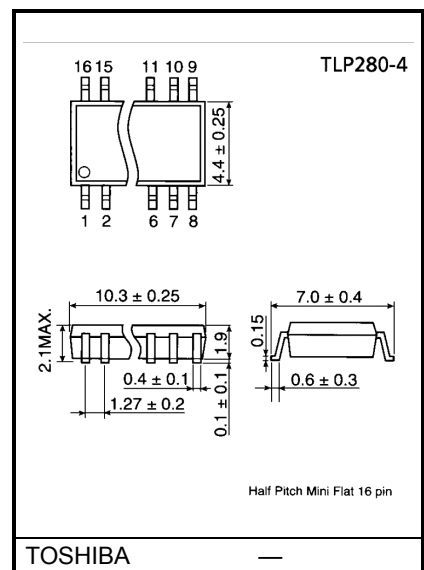
TLP280 and TLP280-4 is a very small and thin coupler, suitable for surface mount assembly in applications such as PCMCIA fax modem, programmable controllers.
 TLP280 and TLP280-4 consist of photo transistor, optically coupled to two gallium arsenide infrared emitting diode connected inverse parallel, and can operate directly by AC input current

- Collector-emitter voltage: 80 V (min)
- Current transfer ratio: 50% (min)
 Rank GB: 100% (min)
- Isolation voltage: 2500 Vrms (min)
- UL recognized: UL1577, file No. E67349
- BSI approved: BS EN 60065: 1994,
 BS EN 41003: 1997
 Certificate No. 8143, 8144

Unit in mm

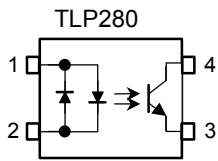


TOSHIBA
 Weight: 0.05 g

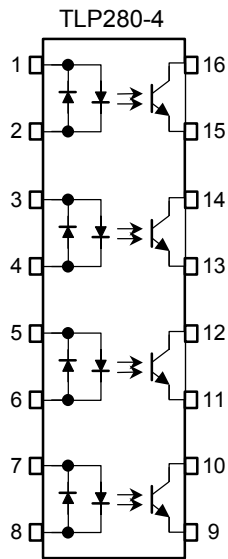


TOSHIBA
 Weight: 0.19 g

Pin Configuration (top view)



- 1 : Anode
Cathode
- 2 : Cathode
Anode
- 3 : Emitter
- 4 : Collector



- 1,3,5,7 : Anode-
Cathode
- 2,4,6,8 : Cathode
Anode
- 9,11,13,15 : Emitter
- 10,12,14,16 : Collector

Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating		Unit
			TLP280	TLP280-4	
LED	Forward current	$I_{F(RMS)}$	±50		mA
	Forward current derating	$\Delta I_F / ^\circ C$	-0.7 (Ta ≥ 53°C)	-0.5 (Ta ≥ 25°C)	mA / °C
	Pulse forward current	I_{FP}	±1 (100µs pulse, 100pps)		A
	Junction temperature	T_j	125		°C
Detector	Collector-emitter voltage	V_{CEO}	80		V
	Emitter-collector voltage	V_{ECO}	7		V
	Collector current	I_C	50		mA
	Collector power dissipation (1 circuit)	P_C	150	100	mW
	Collector power dissipation derating (Ta ≥ 25°C) (1 circuit)	$\Delta P_C / ^\circ C$	-1.5	-1.0	mW / °C
	Junction temperature	T_j	125		°C
Storage temperature range		T_{stg}	-55~125		°C
Operating temperature range		T_{opr}	-55~100		°C
Lead soldering temperature		T_{sol}	260 (10s)		°C
Total package power dissipation (1 circuit)		P_T	200	170	mW
Total package power dissipation derating (Ta ≥ 25°C) (1 circuit)		$\Delta P_T / ^\circ C$	-2.0	-1.7	mW / °C
Isolation voltage (Note)		BV_S	2500 (AC, 1min., R.H. ≤ 60%)		Vrms

(Note): Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ	Max	Unit
LED	Forward voltage	V_F	$I_F = \pm 10 \text{ mA}$	1.0	1.15	1.3	V
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	60	—	pF
Detector	Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 0.5 \text{ mA}$	80	—	—	V
	Emitter-collector breakdown voltage	$V_{(BR)ECO}$	$I_E = 0.1 \text{ mA}$	7	—	—	V
	Collector dark current (Note 1)	I_{CEO}	$V_{CE} = 48 \text{ V}$, Ambient light below (100 lx)	—	0.01 (2)	0.1 (10)	μA
			$V_{CE} = 48 \text{ V}$, $T_a = 85^\circ\text{C}$ Ambient light below (100 lx)	—	2 (4)	50 (50)	μA
Capacitance (collector to emitter)	C_{CE}	$V = 0, f = 1 \text{ MHz}$	—	10	—	pF	

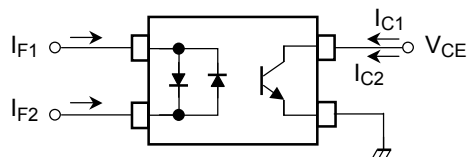
(Note 1): Because of the construction, leak current might be increased by ambient light. Please use photocoupler with less ambient light.

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Current transfer ratio	I_C / I_F	$I_F = \pm 5 \text{ mA}$, $V_{CE} = 5 \text{ V}$ Rank GB	50	—	600	%
			100	—	600	
Saturated CTR	$I_C / I_F (\text{sat})$	$I_F = \pm 1 \text{ mA}$, $V_{CE} = 0.4 \text{ V}$ Rank GB	—	60	—	%
			30	—	—	
Collector-emitter saturation voltage	$V_{CE} (\text{sat})$	$I_C = 2.4 \text{ mA}$, $I_F = \pm 8 \text{ mA}$ $I_C = 0.2 \text{ mA}$, $I_F = \pm 1 \text{ mA}$ Rank GB	—	—	0.4	V
			—	0.2	—	
			—	—	0.4	
Off-state collector current	$I_{C(\text{off})}$	$V_F = \pm 0.7 \text{ V}$, $V_{CE} = 48 \text{ V}$	—	—	10	μA
CTR symmetry	$I_C (\text{ratio})$	$I_C (I_F = -5 \text{ mA}) / I_C (I_F = 5 \text{ mA})$ (Note 2)	0.33	—	3	—

(Note 2):

$$I_C(\text{ratio}) = \frac{I_{C2}(I_F = I_{F2}, V_{CE} = 5\text{V})}{I_{C1}(I_F = I_{F1}, V_{CE} = 5\text{V})}$$



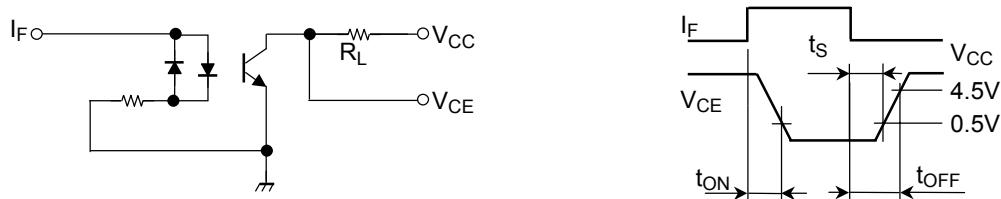
Isolation Characteristics (Ta = 25°C)

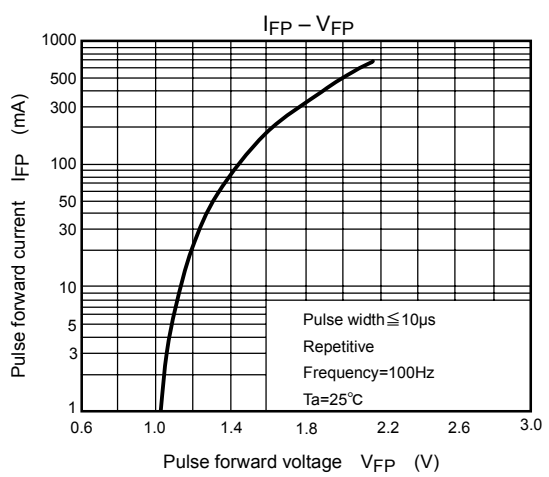
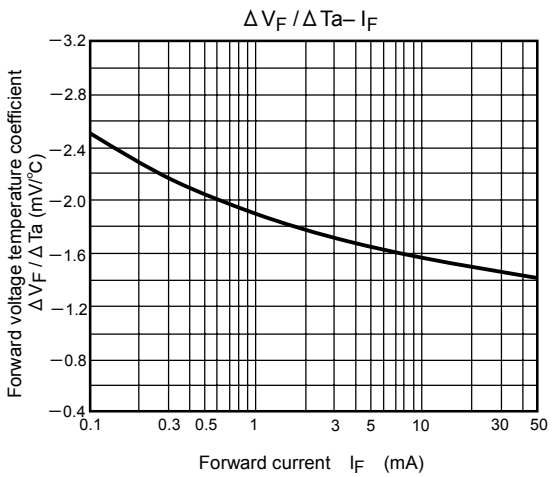
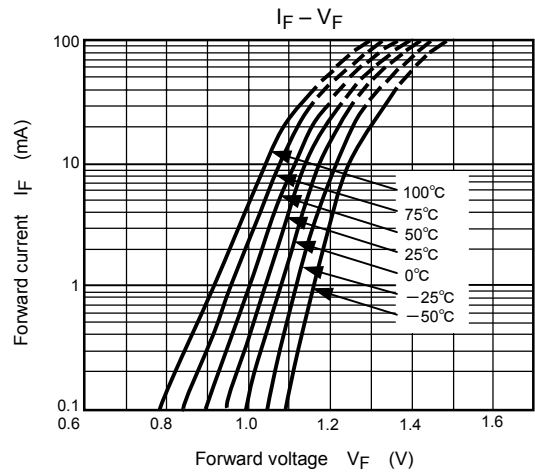
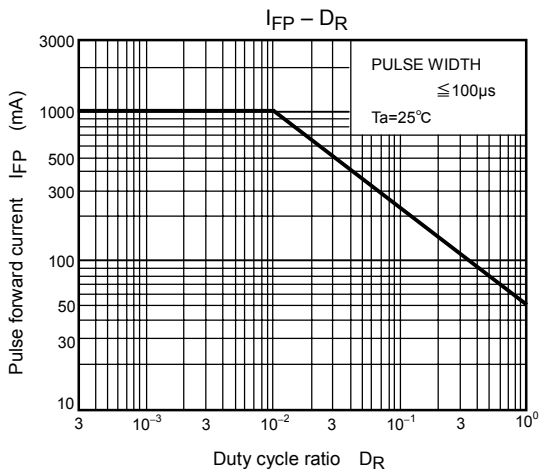
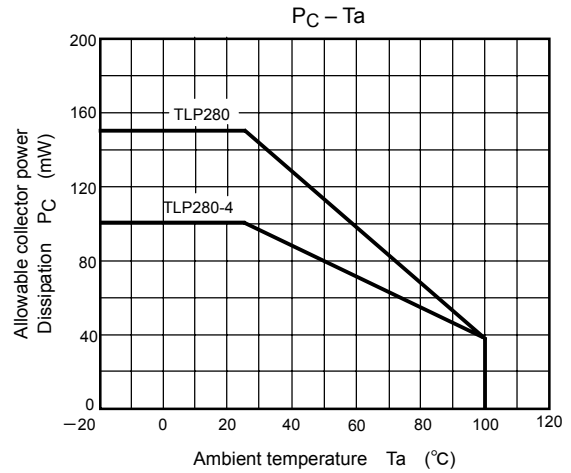
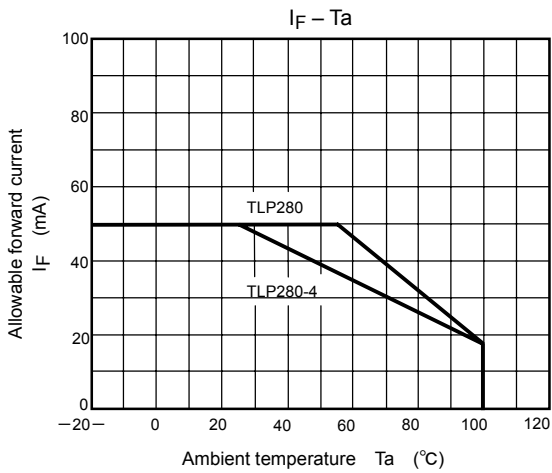
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output	C _S	V _S = 0V, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	—	Ω
Isolation voltage	BV _S	AC, 1 minute	2500	—	—	V _{rms}
		AC, 1 second, in oil	—	5000	—	V _{rms}
		DC, 1 minute, in oil	—	5000	—	V _{dc}

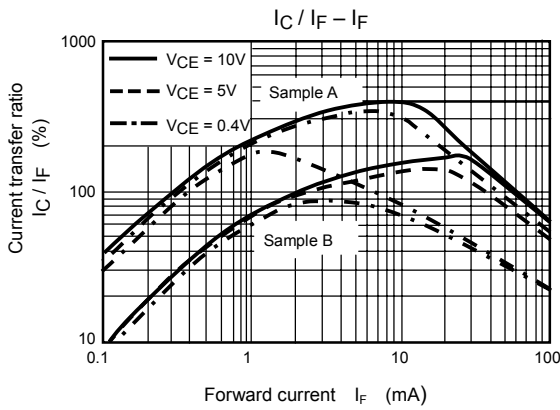
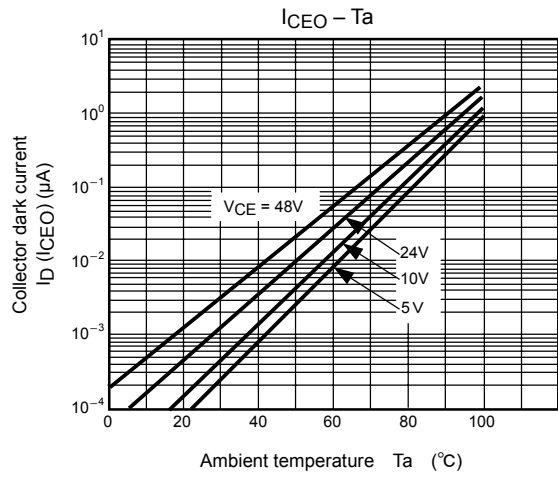
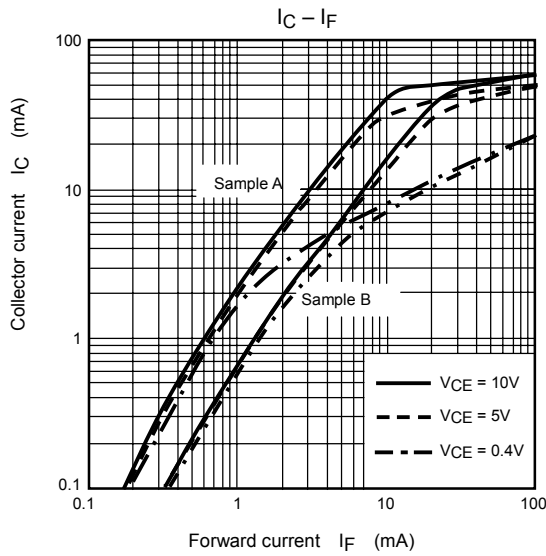
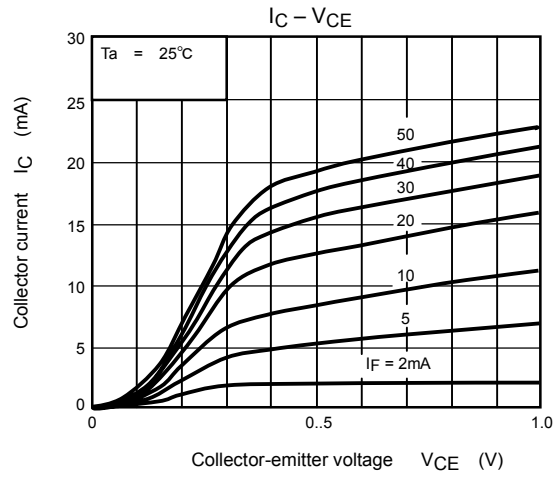
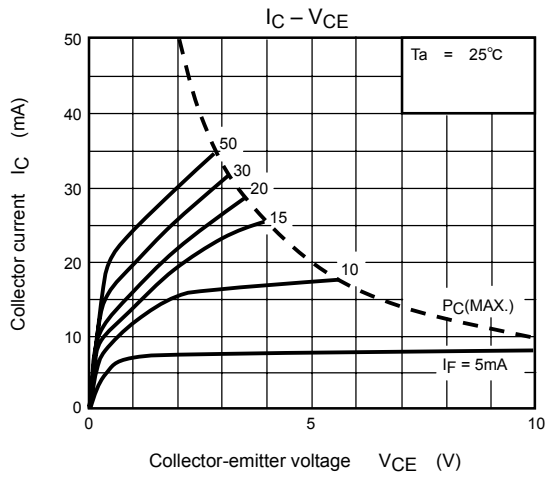
Switching Characteristics (Ta = 25°C)

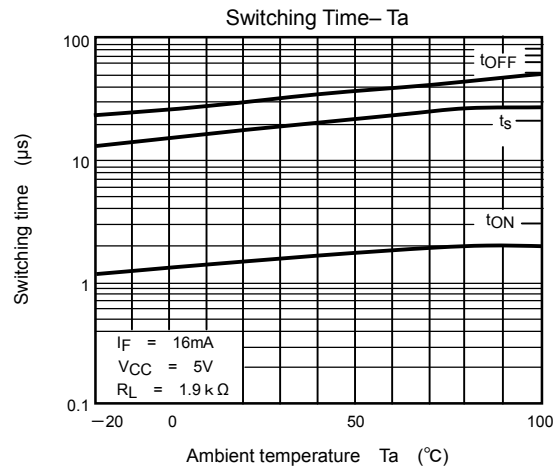
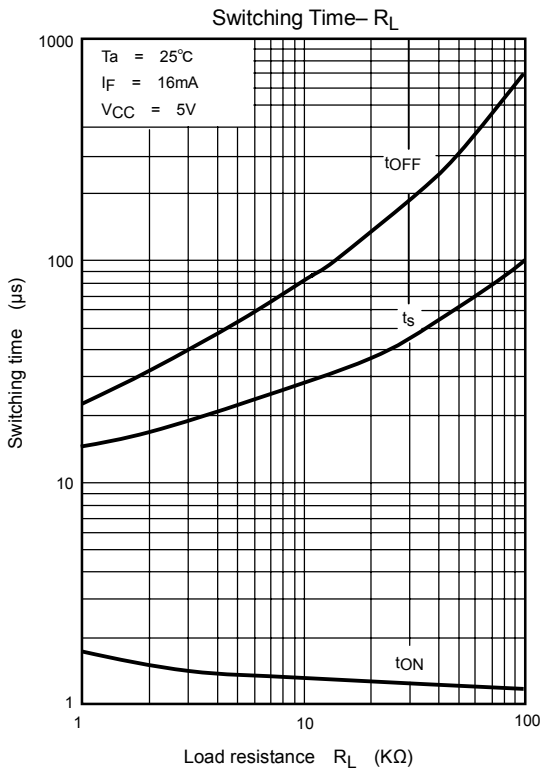
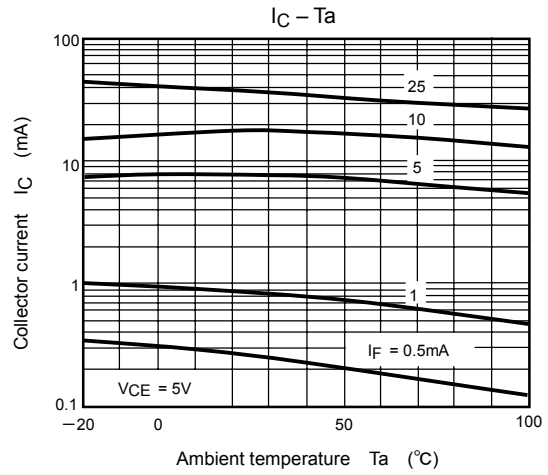
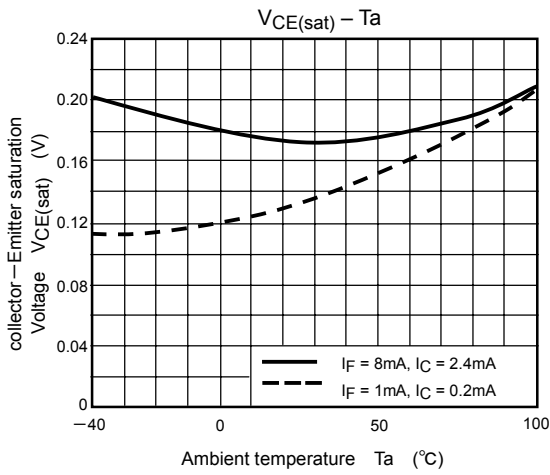
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Rise time	t _r	V _{CC} = 10 V, I _C = 2 mA R _L = 100Ω	—	2	—	μs
Fall time	t _f		—	3	—	
Turn-on time	t _{on}		—	3	—	
Turn-off time	t _{off}		—	3	—	
Turn-on time	t _{ON}	R _L = 1.9 kΩ V _{CC} = 5 V, I _F = ±16 mA (Fig.1)	—	2	—	μs
Storage time	t _s		—	25	—	
Turn-off time	t _{OFF}		—	40	—	

(Fig. 1): Switching time test circuit









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000707EBC

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